

# MULTILAYER LAUE LENSES FOR HARD X-RAY MICROSCOPY

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PHOTON SCIENCES

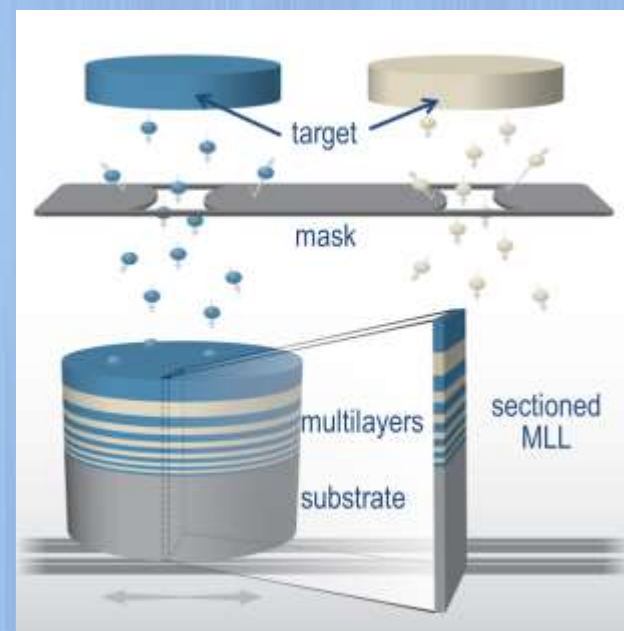
## Multilayer Laue lenses

Multilayer Laue lenses (MLLs) optics offer great promise for focusing hard x-rays to nanometer level. Fabrication of MLLs rely on deposition of a depth graded multilayer thin film with layer thicknesses increasing progressively along the normal direction. Layer thicknesses typically varies between 2 and 25 nm. After the multilayer growth, multilayer is sectioned to produce an optical structure with a **very high aspect ratio** (section depth to zone width). For hard X-rays, the thinner outermost layer and the larger width achievable enable the MLL to simultaneously achieve higher **spatial resolution** and diffraction efficiency than conventional zone plates. The fabrication process for an ideal MLL reside in the **accurate placement of the layers** and **quality of the sectioning** – thickness, profile, roughness, minimal introduction of defects - for the layers to diffract in phase at the focus with **maximum efficiency**. Maintaining these requirement for high aspect ratios structures presents enormous challenges as the aperture size continues to increase.

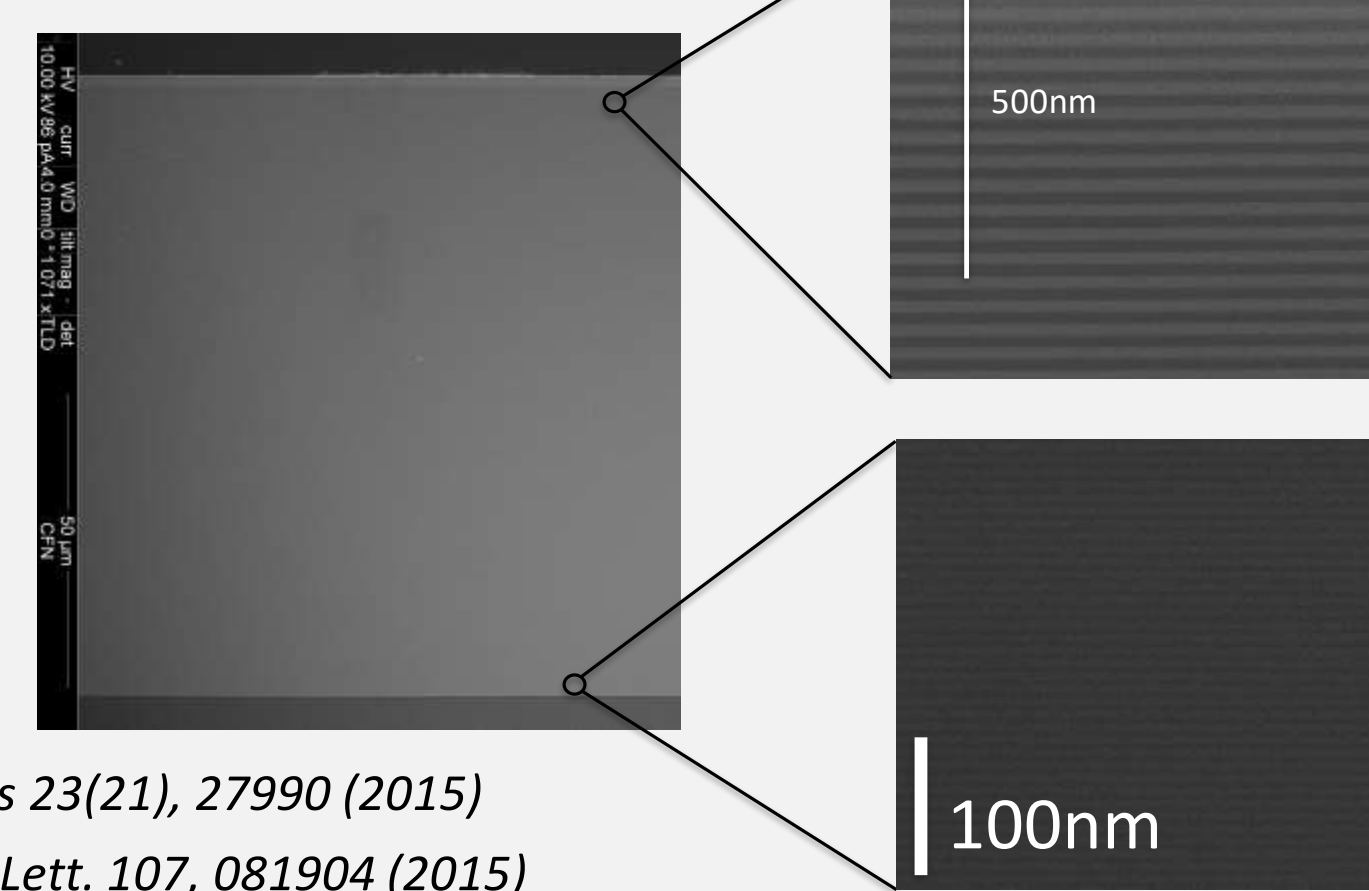
## Multilayer deposition



Deposition chamber in our labs at NSLS-II



Successful deposition of a **102µm thick multilayer for MLL**, nearly twice thicker than previously reported

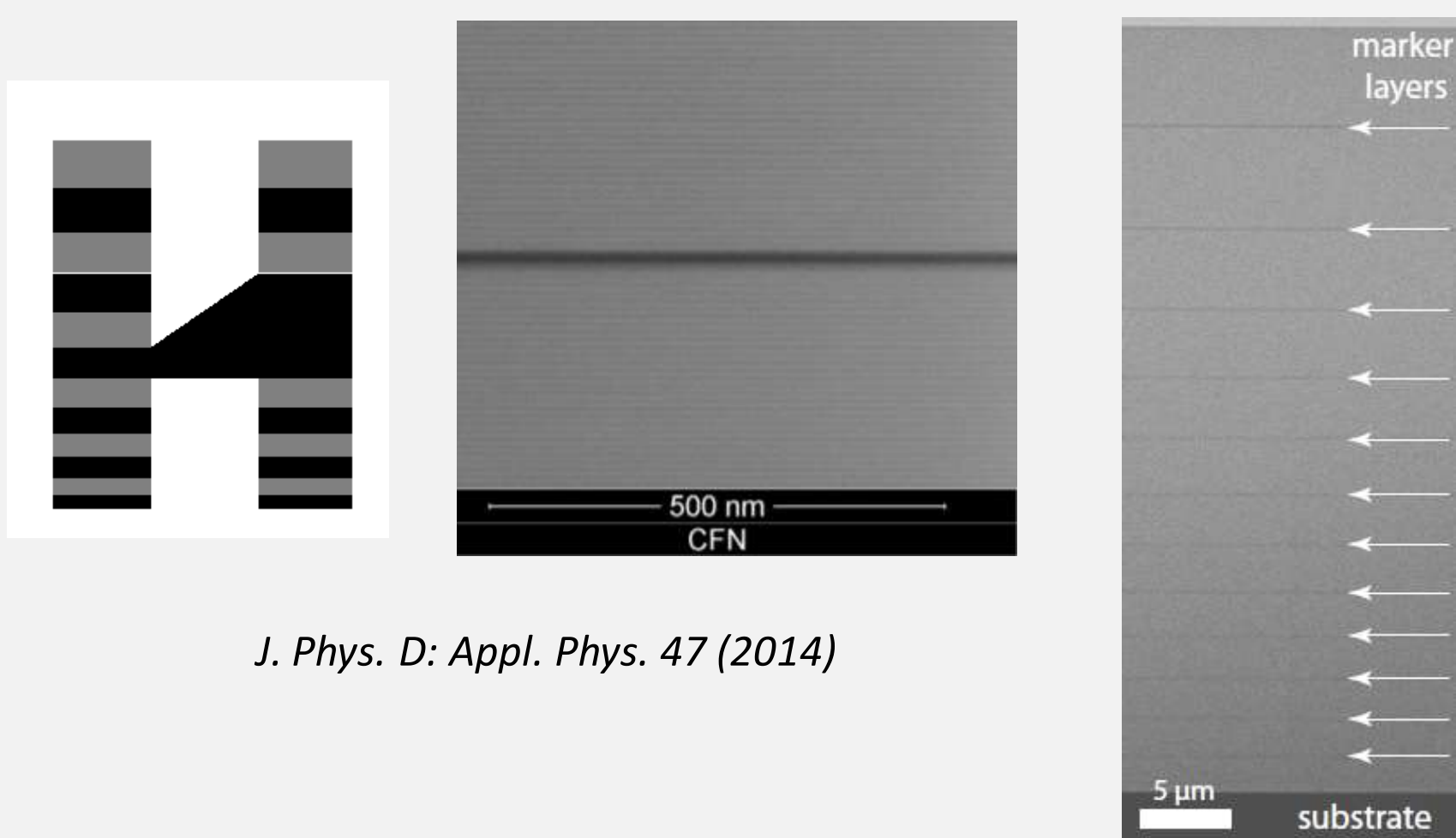


*Opt. Express* 23(21), 27990 (2015)  
*Appl. Phys. Lett.* 107, 081904 (2015)

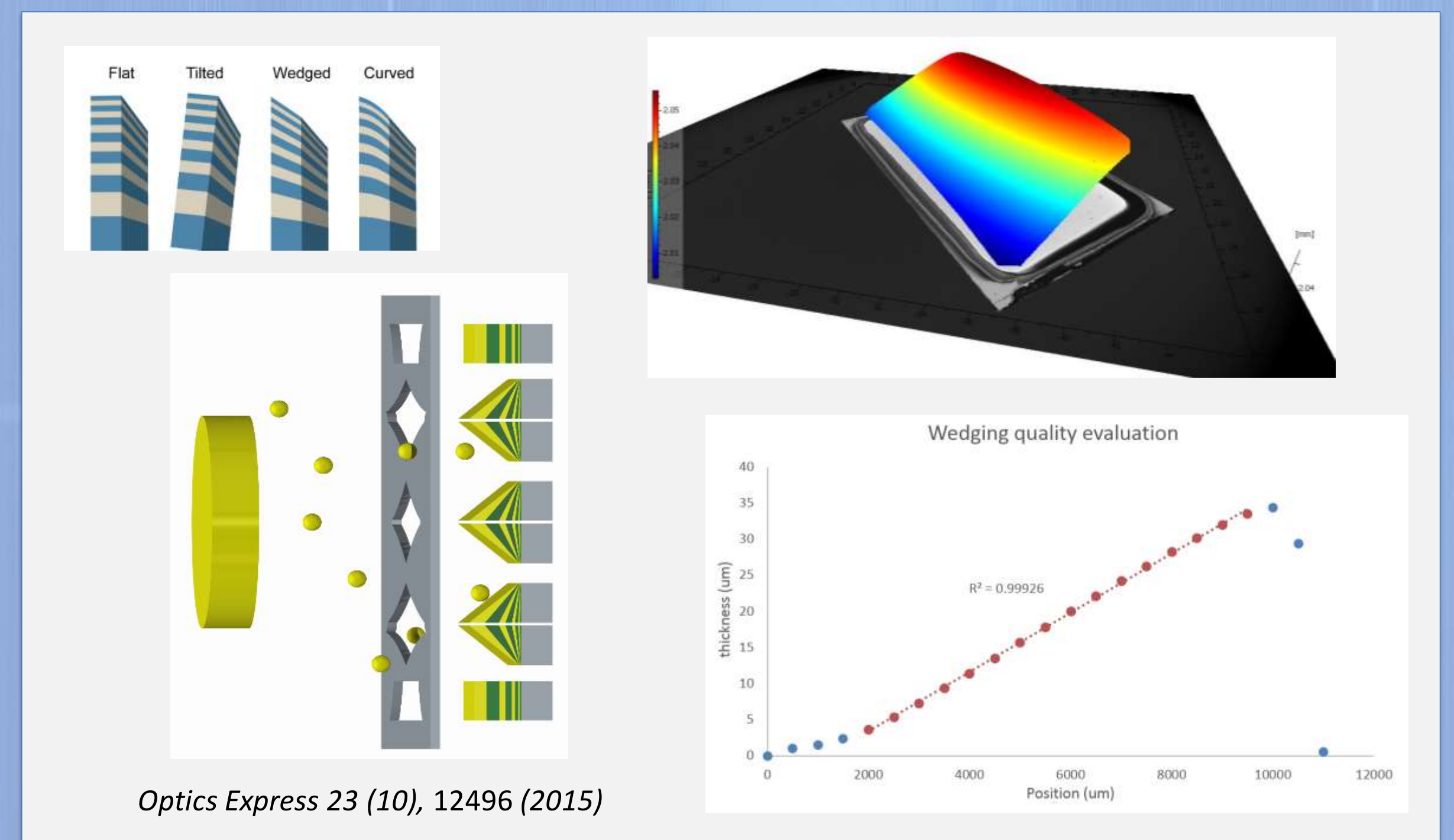
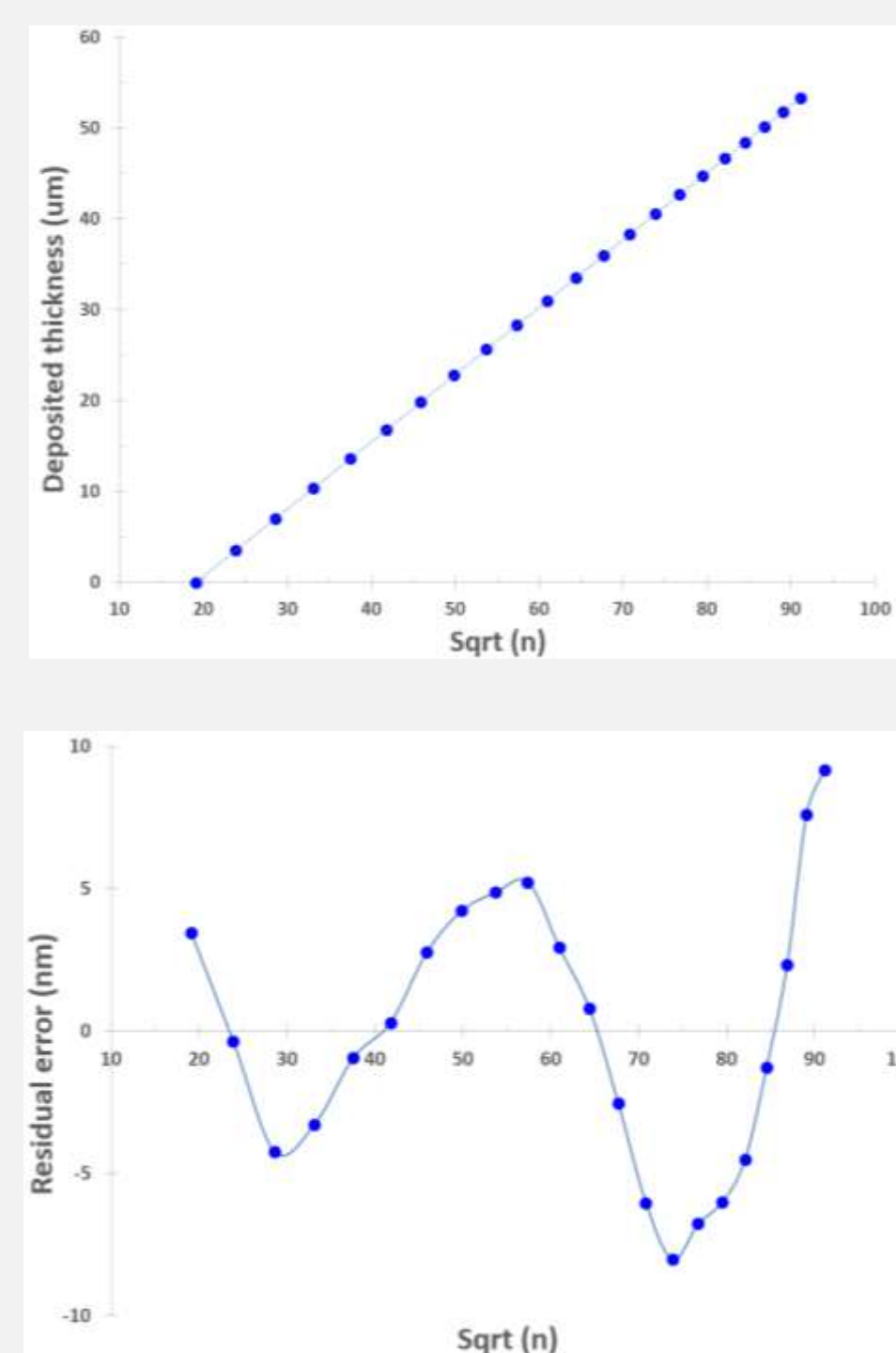
- Flat substrate
- Deposition rate calibration
- Deposition of the multilayer by sputtering
  - 2 materials deposited alternatively
  - Low interfacial roughness needed
  - Several thousands of layers
  - High thermal and temporal stability

## Metrology

Thanks to markers built in the multilayer, post-growth ex-situ characterization via SEM can be used as a metrology tool to accurately evaluate the zone placement error



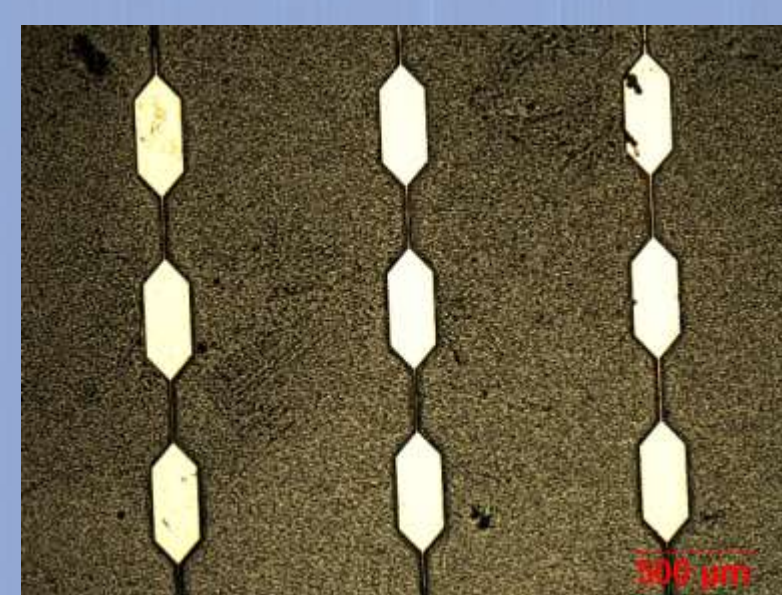
*J. Phys. D: Appl. Phys.* 47 (2014)



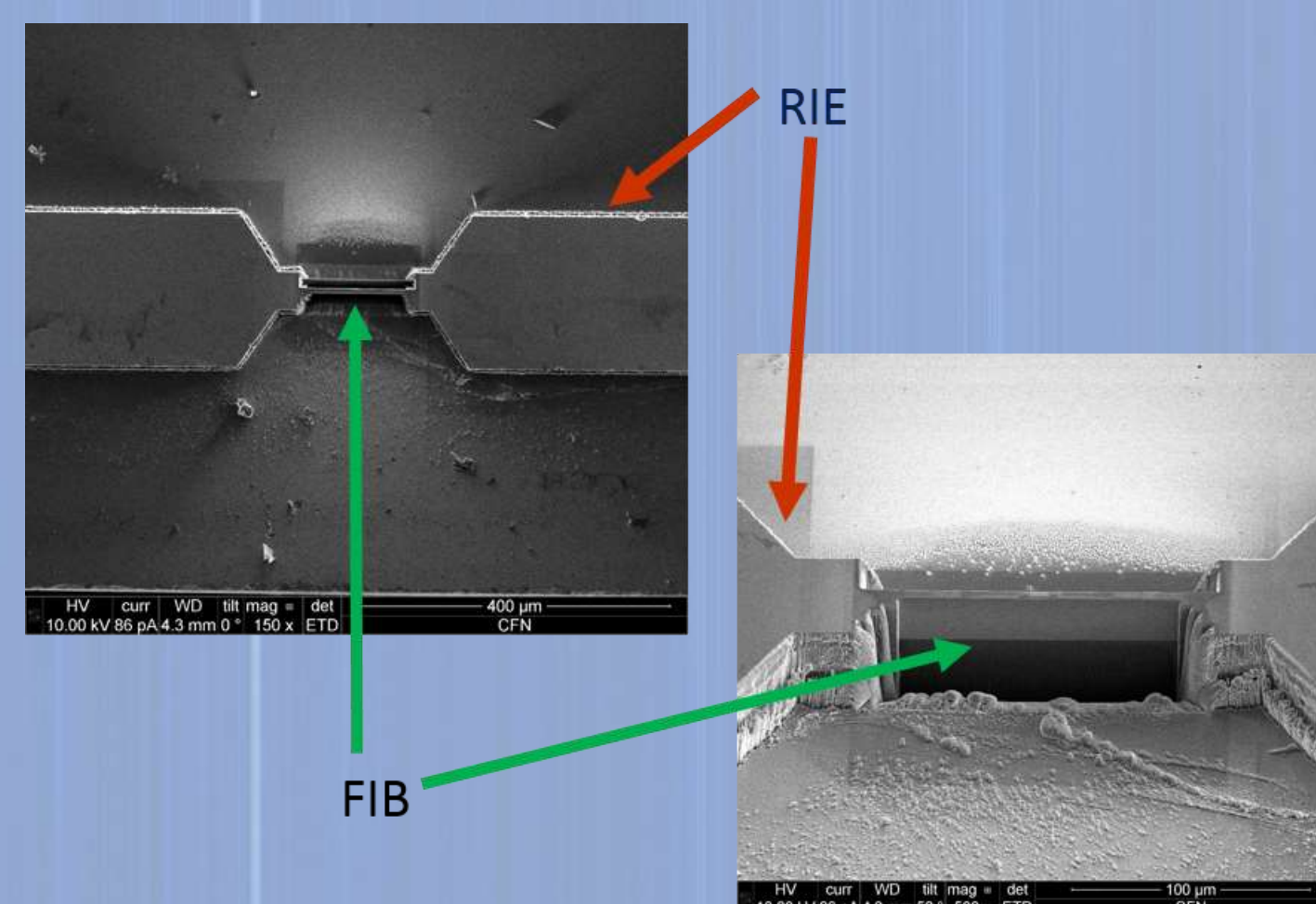
*Optics Express* 23 (10), 12496 (2015)

## Sectioning

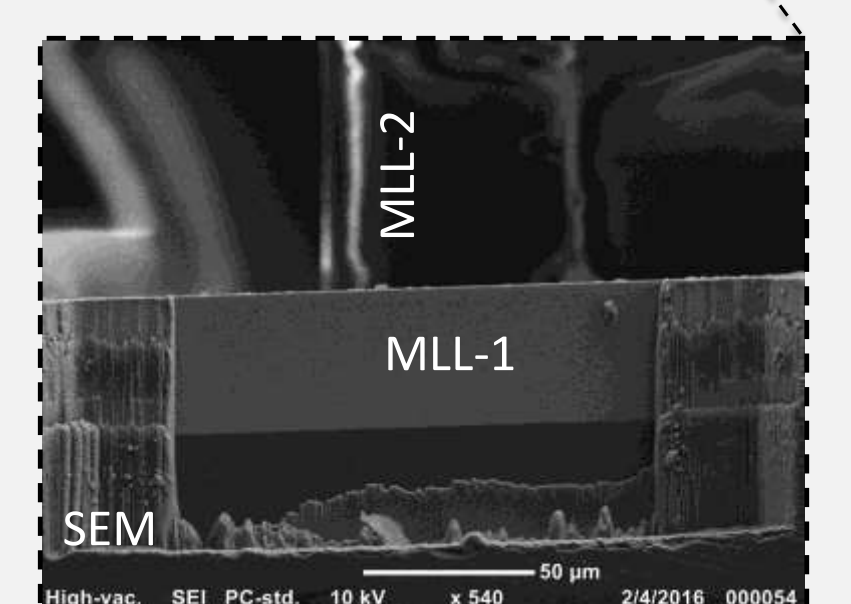
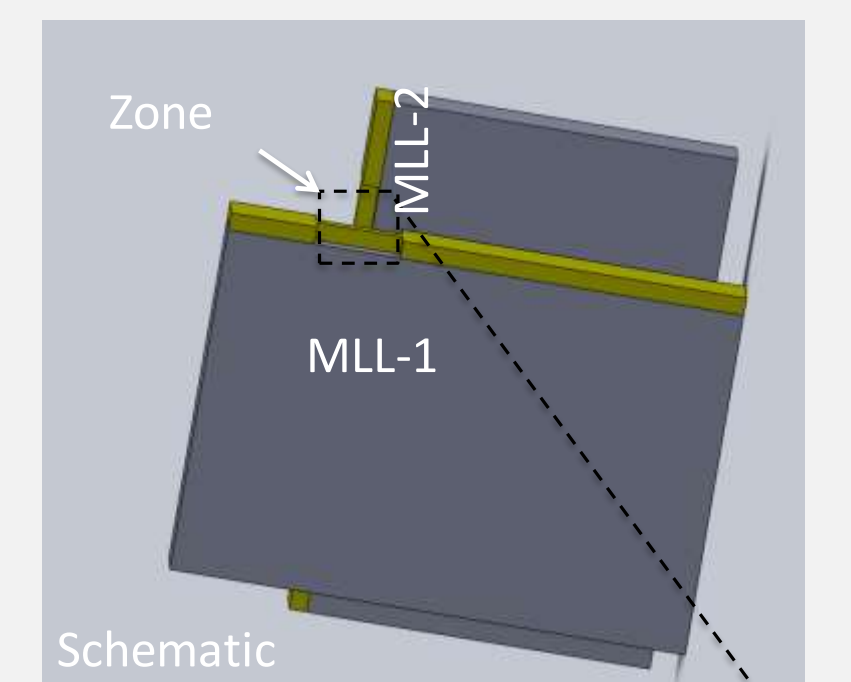
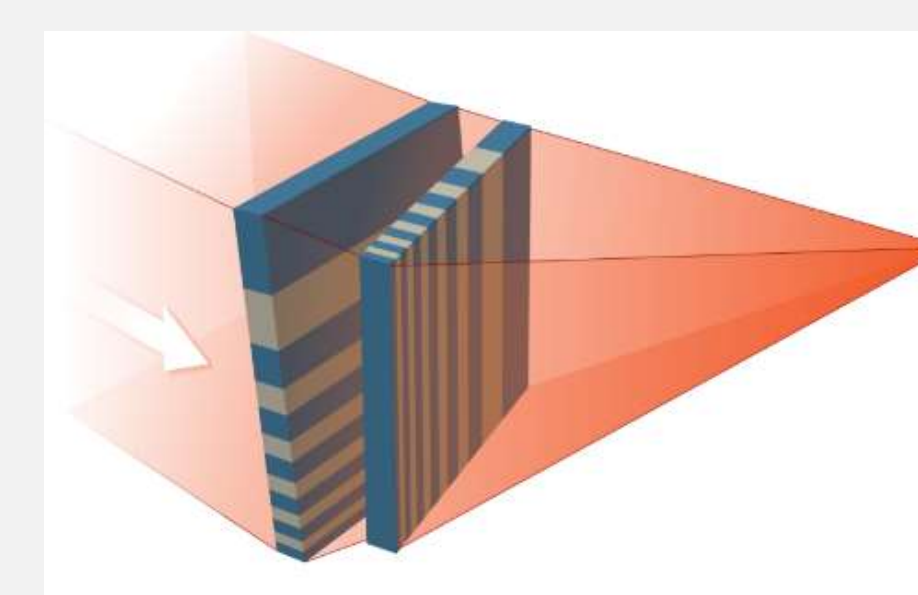
- High aspect ratio (1:5 to 1:20)
- Mechanical stability
- Multi-material
- Micron size sleeves
- Controlled section thickness for maximum performances
- Minimum damage



US patent #9,153,453



2D focusing achieved by using 2 crossed MLL



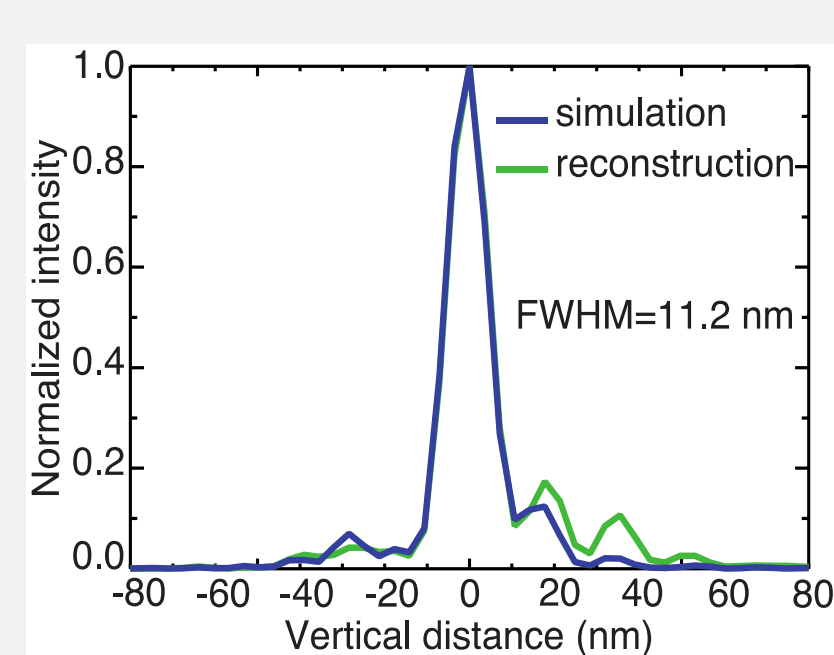
*Appl. Phys. Lett.* 108, 261102 (2016)

- Align independently
- Monolithic optic

## Focusing performances

### Flat MLLs

43 microns thick ML  
WSi<sub>2</sub>/Si  
~6500 layers  
Outermost zone = 4nm  
Focal length = 4.2mm  
12keV



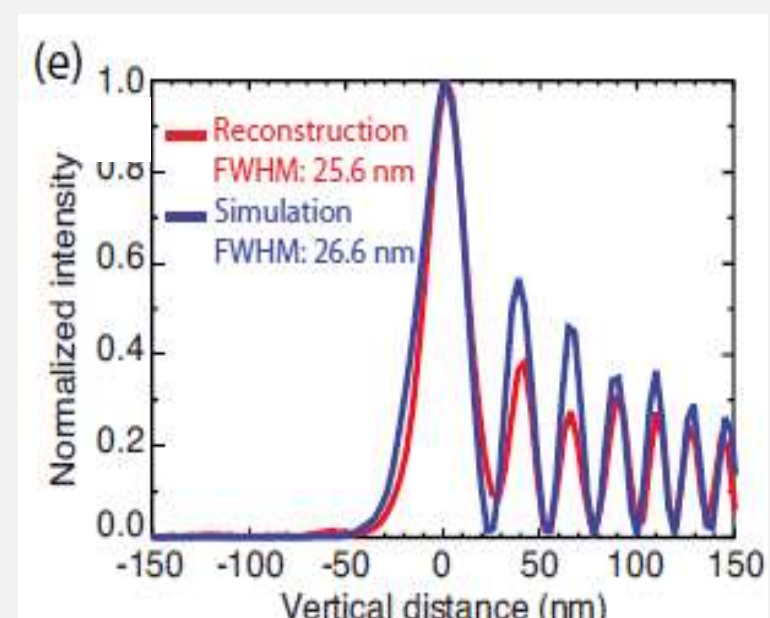
Line focus = 11.2nm

Installed at 3-ID (HXN) @NSLS-II

*Scientific Report* 3 (2013)

### Wedged MLLs

31microns thick ML  
WSi<sub>2</sub>/Si  
~7650 layers  
Outermost zone = 2.8nm  
Focal length = 3.2mm  
14.6keV



Line focus = 26nm  
Efficiency ~27%

Tested at 1-BM and 34-ID-C at APS  
*Opt. Express* 23, 12496 (2015)



MLL optics delivering a 15 x 15nm<sup>2</sup> focus at 12keV to users for science experiments at the 3-ID (HXN) beamline of the NSLS-II



2016 Microscopy Innovation award  
2016 R&D100 award

### Monolithic (Bonded MLLs) optic

43 microns thick ML and 53 microns thick ML  
WSi<sub>2</sub>/Si

Tested at 3-ID (HXN) at NSLS-II @12keV

Horizontal and vertical plane separated by 221µm, consistent with metrology

Focus sizes are :

- 12 nm at horizontal focal plane
- 24 nm at vertical focal plane

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## Acknowledgements

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